

### **DATA SHEET**

## KBP005 THRU KBP10

# TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER



## **VOLTAGE RANGE-50 to 1000 Volts CURRENT-2.0 Amperes**

#### **FEATURES**

Ideal for printed circuit board

Surge overload rating: 50 Amperes peak

High temperature soldering : 260°C / 10 seconds at term<sup>inals</sup> Pb free product at available : 99% Sn above meet RoHS

environment substance directive request

#### **MECHANICAL DATA**

Case:Molded plastic

Epoxy: UL 94V-0 rate flame retardant

Lead: MIL-STD-202E,Method 208 guaranteed Polarity: Symbols molded or marked on body

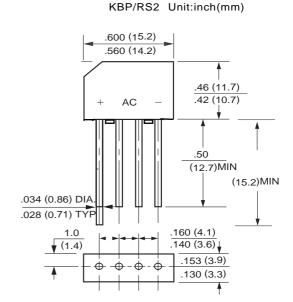
Mounting position: Any Weight: 2.74 grams

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.



|   |           | SYMBOL | KBP005       | KBP01 | KBP02 | KBP04 | KBP06 | KBP08 | KBP10 | UNITS |
|---|-----------|--------|--------------|-------|-------|-------|-------|-------|-------|-------|
| Maximum Recurrent Peak Reverse Voltage                                    |           | VRRM   | 50           | 100   | 200   | 400   | 600   | 800   | 1000  | Volts |
| Maximum RMS Bridge Input Voltage  |           | VRMS   | 35           | 70    | 140   | 280   | 420   | 560   | 700   | Volts |
| Maximum DC Blocking Voltage   |           | VDC    | 50           | 100   | 200   | 400   | 600   | 800   | 1000  | Volts |
| Maximum Average Forward Output TA = 50                                    |           | Ю      | 2.0          |       |       |       |       |       |       | Amps  |
| Peak Forward Surge Current 8.3 ms single half sine-wave                   |           | IFSM   | 50           |       |       |       |       |       |       | Amps  |
| superimposed on rated load (JEDEC method)                                 |           |        |              |       |       |       |       |       |       |       |
| Maximum Forward Voltage Drop per element at 1.0A DC                       |           | VF     | 1.0          |       |       |       |       |       |       | Volts |
| Maximum DC Reverse Current at<br>Rated DC Blocking Voltage per<br>element | @TA = 25  | IR     | 5            |       |       |       |       |       |       | μΑтр  |
|   | @TA = 100 |        | 500          |       |       |       |       |       |       |       |
| I2t Rating for Fusing(t<8.3ms)  |           | I2t    | 10           |       |       |       |       |       |       | A2Sec |
| Typical Junction Capacitance(Note1)                                       |           | CJ     | 15           |       |       |       |       |       |       | pF    |
| Operating Temperature Range   |           | TJ     | -55 to + 150 |       |       |       |       |       |       |       |
| Storage Temperature Range   |           | TSTG   | -55 to + 150 |       |       |       |       |       |       |       |

NOTES: 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts

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<sup>2.</sup>Thermal Resistance from Junction to Ambient and from junction to lead mounted on P.C.B with 0.47x0.47"(12x12mm)copperpads.

## **DEVICE CHARACTERISTICS**

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FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

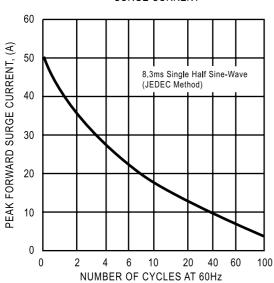


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

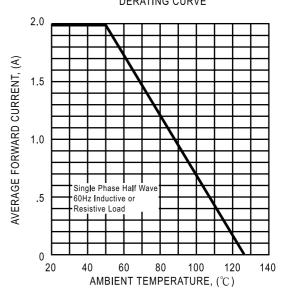


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

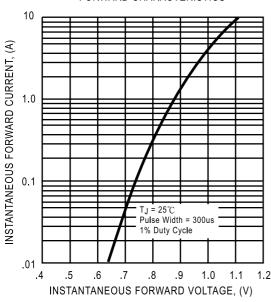


FIG. 4 - TYPICAL REVERSE

